



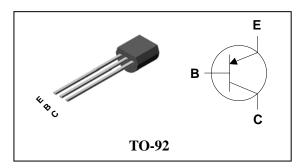
Description

- General purpose amplifier
- High voltage application

Features

- High collector breakdown voltage : $V_{CBO} = -160V$, $V_{CEO} = -160V$
- Low collector saturation voltage : $V_{CE(sat)}$ =-0.5V(MAX.)
- Complementary pair with 2N5551

PIN Connection



Ordering Information

Type NO.	Marking	Package Code	
2N5401	2N5401□	TO-92	

□ : Year & Week Code

Absolute maximum ratings

(Ta=25°C)

Characteristic	Symbol	Ratings	Unit
Collector-Base voltage	V_{CBO}	-160	V
Collector-Emitter voltage	V_{CEO}	-160	V
Emitter-Base voltage	V_{EBO}	-5	V
Collector current	${ m I}_{ m C}$	-600	mA
Collector dissipation	P _C	625	mW
Junction temperature	T_{j}	150	°C
Storage temperature	T_{stg}	-55~150	°C

KSD-T0A076-000

2N5401

Electrical Characteristics

(Ta=25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-Base breakdown voltage	BV_CBO	I _C =-100μA, I _E =0	-160	-	-	V
Collector-Emitter breakdown voltage	BV_CEO	$I_C=-1$ mA, $I_B=0$	-160	-	-	V
Emitter-Base breakdown voltage	BV_{EBO}	I _E =-10μA, I _C =0	-5	-	-	V
Collector cut-off current	I_{CBO}	V _{CB} =-120V, I _E =0	-	-	-100	nA
Emitter cut-off current	I_{EBO}	V_{EB} =-3V, I_{C} =0	_	-	-100	nA
DC current gain	h _{FE (1)}	V_{CE} =-5V, I_{C} =-1mA	50	-		-
DC current gain	h _{FE (2)}	V _{CE} =-5V, I _C =-10mA	60	-	240	-
DC current gain	h _{FE (3)}	V _{CE} =-5V, I _C =-50mA	50	-		-
Collector-Emitter saturation voltage	V _{CE(sat)(1)} *	I _C =-10mA, I _B =-1mA	_	-	-0.2	V
Collector-Emitter saturation voltage	V _{CE(sat)(2)} *	I _C =-50mA, I _B =-5mA	_	-	-0.5	V
Base-Emitter saturation voltage	V _{BE(sat)(1)} *	I _C =-10mA, I _B =-1mA	_	-	-1	V
Base-Emitter saturation voltage	V _{BE(sat)(2)*}	I _C =-50mA, I _B =-5mA	_	-	-1	V
Transition frequency	f _T	V _{CE} =-10V, I _C =-10mA	100	-	400	MHz
Collector output capacitance	C _{ob}	V _{CB} =-10V, I _E =0, f=1MHz	-	-	6	pF

^{* :} Pulse Tester : Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%

Electrical Characteristic Curves

Fig. 1 P_C.T_a

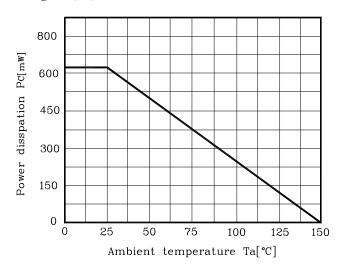
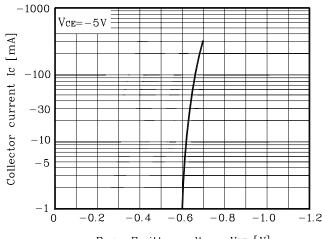


Fig. 2 $I_{C}\,$ - $\,V_{BE}\,$



Base-Emitter voltage VBE [V]

Fig. 3 $f_T\,$ - $\,I_C\,$

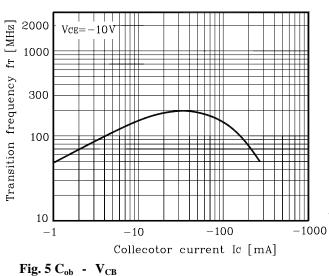
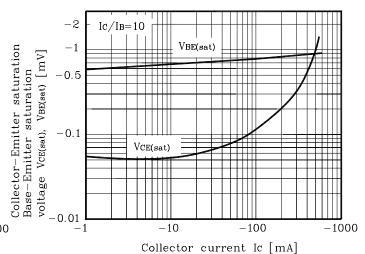
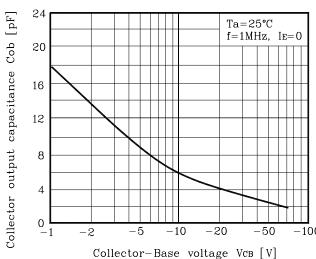


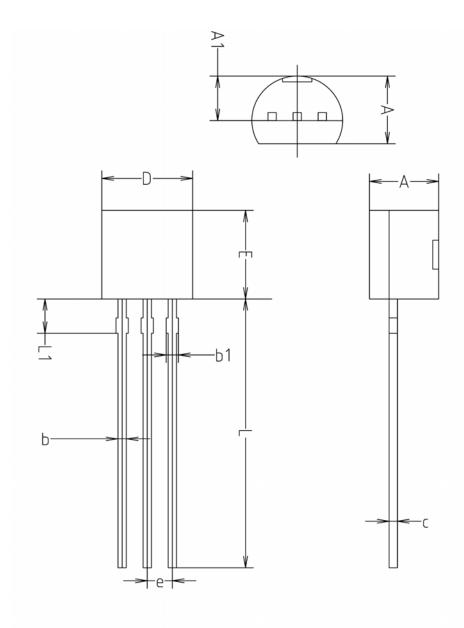
Fig. 4 $V_{CE(sat)}$, $V_{BE(sat)}$ - I_C





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Outline Dimension



6144661	MILLMETERS(mm)			
SYMBOL	MINIMUM	NOMINAL	MAXIMUM	
Α	3.40	3.50	3.66	
A1	2.46	2.51	2.59	
b	0.39	0.44	0.53	
b1	0.39	_	0.63	
С	0.35	0.42	0.47	
D	4.48	4.60	4.70	
Ε	4.48	4.60	4.70	
е	1.17	1.27	1.37	
L	13.70	14.00	14.77	
L1	1.55	1.70	2.15	

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